VS-MBRB20..CTPbF, VS-MBR20..CT-1PbF Series

Vishay Semiconductors

RoHS

COMPLIANT

HALOGEN

FREE

High Performance Schottky Rectifier, 2 x 10 A



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ISHA'



TO-262

D²PAK

Base common cathode 2 2 2 10 Common 0 3

common cathode 2 0 2 10 Common 0 3 Anode cathode Anode

Base

Anode cathode Anode

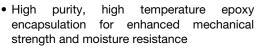
VS-MBRB20..CTPbF

VS-MBR20..CT-1PbF

PRODUCT SUMMARY	
Package	TO-263AB (D ² PAK), TO-262AA
I _{F(AV)}	2 x 10 A
V _R	35 V, 45 V
V _F at I _F	0.72 V
I _{RM} max.	15 mA at 125 °C
T _J max.	150 °C
Diode variation	Common cathode
E _{AS}	8 mJ

FEATURES

- 150 °C T_J operation
- Center tap D²PAK and TO-262 packages
- Low forward voltage drop
- High frequency operation



- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform (per device)	20	٨			
I _{FRM}	T _C = 135 °C (per leg)	20	A			
V _{RRM}		35, 45	V			
I _{FSM}	t _p = 5 μs sine	1060	A			
V _F	10 A _{pk} , T _J = 125 °C	0.57	V			
TJ	Range	-65 to +150	°C			

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-MBRB2035CTPbF VS-MBR2035CT-1PbF	VS-MBRB2045CTPbF VS-MBR2045CT-1PbF	UNITS	
Maximum DC reverse voltage	V _R	35	45	V	
Maximum working peak reverse voltage	V _{RWM}		40	v	

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ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	7	TEST CONDITIONS	VALUES	UNITS	
Maximum average per leg		T _C = 135 °C, rate	d V-	10		
forward current per device	I _{F(AV)}	$T_{\rm C} = 155$ C, fate	u v _R	20		
Peak repetitive forward current per leg	I _{FRM}	Rated V _R , square wave, 20 kHz, T _C = 135 °C		20	1	
Non-repetitive peak surge current		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	1060	A	
Non-repetitive peak surge current	IFSM	Surge applied at single phase, 60	rated load conditions halfwave, Hz	150		
Non-repetitive avalanche energy per leg	E _{AS}	$T_J = 25 \text{ °C}, I_{AS} = 25 \text{ °C}$	2 A, L = 4 mH	8	mJ	
Repetitive avalanche current per leg	I _{AR}	Current decaying Frequency limited V _A = 1.5 x V _R typi	, ,	2	А	

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
		20 A	T _J = 25 °C	0.84	
Maximum forward voltage drop	V _{FM} ⁽¹⁾	10 A	T _{.1} = 125 °C	0.57	V
		20 A	1j = 125 0	0.72	
Maximum instantaneous	I _{BM} ⁽¹⁾	T _J = 25 °C	Rated DC voltage	0.1	mA
reverse current	IRM \''	T _J = 125 °C		15	
Threshold voltage	V _{F(TO)}			0.354	V
Forward slope resistance	r _t	$T_J = T_J maximum$		17.6	mΩ
Maximum junction capacitance	CT	$V_{R} = 5 V_{DC}$ (test signal rang	ge 100 kHz to 1 MHz), 25 °C	600	pF
Typical series inductance	L _S	Measured from top of term	inal to mounting plane	8.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

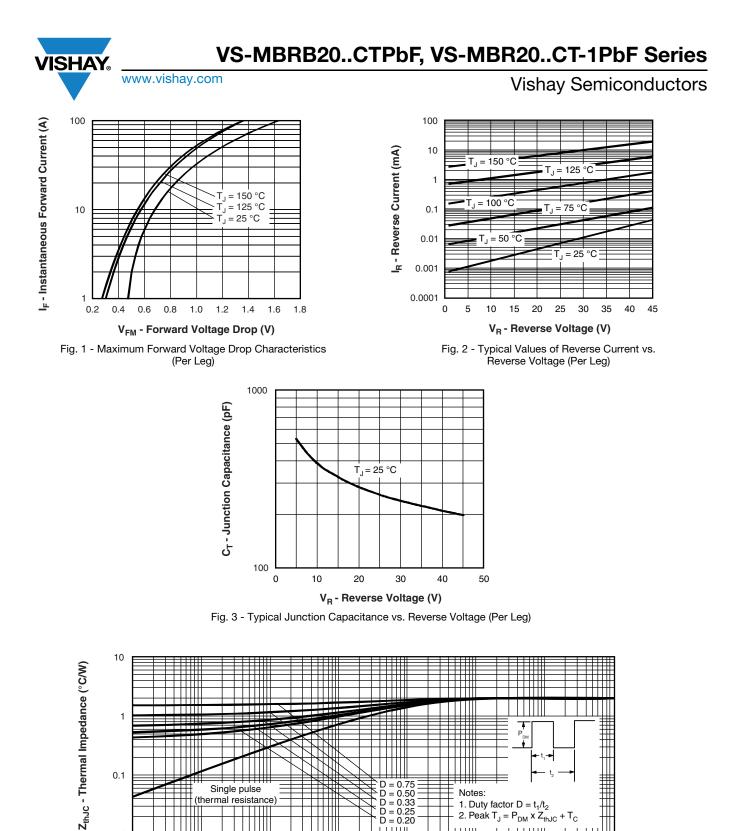
THERMAL - MECHNICAL S	PECIFICA	TIONS			
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction temperature range	TJ		-65 to +150	°C	
Maximum storage temperature range	T _{Stg}		-65 to +175	U	
Maximum thermal resistance, junction to case per leg	R _{thJC}	DC operation	2.0	°C/W	
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.50	C/W	
Approximate weight			2	g	
			0.07	oz.	
Mounting torque	ı	Non-lubricated threads	6 (5)	kgf · cm	
Mounting torque maximun	ı	Non-hubricated threads	12 (10)	(lbf · in)	
		C_{222} at the TO 262AD (D^2DAK)	MBRB2035CT		
		Case style TO-263AB (D ² PAK)	MBRB2045CT		
Marking device		Occess at the TO OCCAA	MBR2035CT-1		
		Case style TO-262AA	MBR2045CT-1		

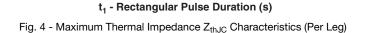
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0.01

D = 0.75 D = 0.50

D = 0.33

D = 0.25

= 0.20 D

0.1

Notes:

1

1. Duty factor $D = t_1/t_2$

2. Peak $T_J = P_{DM} \times Z_{thJC} + T_C$

1 1 1 1 1 1 1

10

100

0.0001

Single pulse

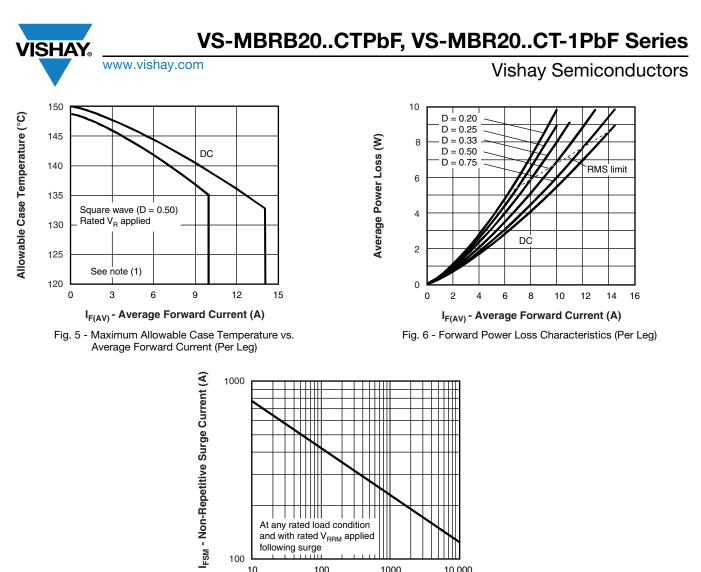
(thermal resistance)

0.001

0.1

0.01 0.00001

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100 1000 10 000

 t_p - Square Wave Pulse Duration (µs) Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$; $I_R at V_{R1} = Rated V_R$

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ORDERING INFORMATION TABLE

VISHA

Device code	VS-	MBR	в	20	45	СТ	-1	TRL	PbF
	1	2	3	4	5	6	7	8	9
		- Ess - • B • N - Cur - Voli	ential pa = D ² PA one = T rent rati tage rati	O-262 [ng (20 =	7 Nor 7 = - ² 20 A)	ne 1 35 = 45 =	= 35 V = 45 V]	
	8	• -1 - • N • TI		62		ne oriented			• ·
	9			id (Pb)-f Pb)-free	•				be)

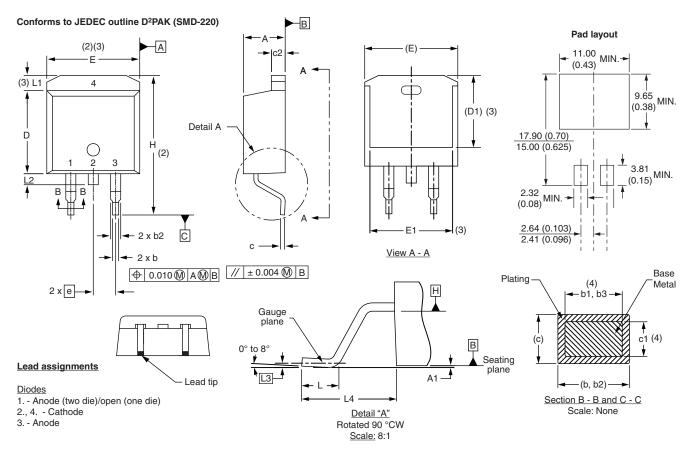
ORDERING INFORMAT	ION (Example)		
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-MBRB2035CTPBF	50	1000	Antistatic plastic tube
VS-MBR2035CT-1PBF	50	1000	Antistatic plastic tube
VS-MBRB2035CTTRLP	800	800	13" diameter reel
VS-MBRB2035CTTRRP	800	800	13" diameter reel
VS-MBRB2045CTPBF	50	1000	Antistatic plastic tube
VS-MBR2045CT-1PBF	50	1000	Antistatic plastic tube
VS-MBRB2045CTTRLP	800	800	13" diameter reel
VS-MBRB2045CTTRRP	800	800	13" diameter reel

LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?95014				
Part marking information	www.vishay.com/doc?95008			
Packaging information	www.vishay.com/doc?95032			
SPICE model	www.vishay.com/doc?95504			

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D²PAK, TO-262



DIMENSIONS - D²PAK in millimeters and inches

SHA

SYMBOL	MILLIN	MILLIMETERS		HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
с	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	BSC	0.100	BSC	
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25	BSC	0.010	BSC	
L4	4.78	5.28	0.188	0.208	

INCHES

MILLIMETERS

⁽⁷⁾ Outline conforms to JEDEC outline TO-263AB

Notes

 $^{(1)}\,$ Dimensioning and tolerancing per ASME Y14.5 M-1994 $\,$

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

- $^{(3)}\,$ Thermal pad contour optional within dimension E, L1, D1 and E1
- ⁽⁴⁾ Dimension b1 and c1 apply to base metal only
- ⁽⁵⁾ Datum A and B to be determined at datum plane H
- ⁽⁶⁾ Controlling dimension: inch

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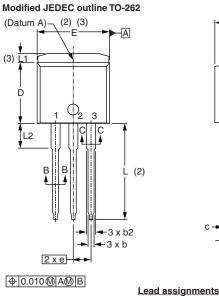
Outline Dimensions

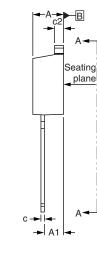
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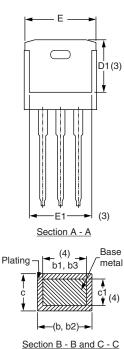
D²PAK, TO-262



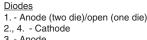
DIMENSIONS - TO-262 in millimeters and inches

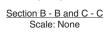






Lead tip





SYMBOL	MILLIN	METERS	INCI	NOTES	
	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100	BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Controlling dimension: inches

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actual package outline

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the

3. - Anode



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